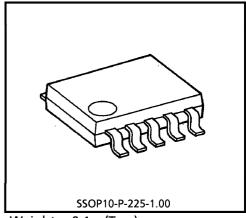
TOSHIBA BI-CMOS INTEGRATED CIRCUIT SILICON MONOLITHIC

# TB1010F

# **CR TIMER**

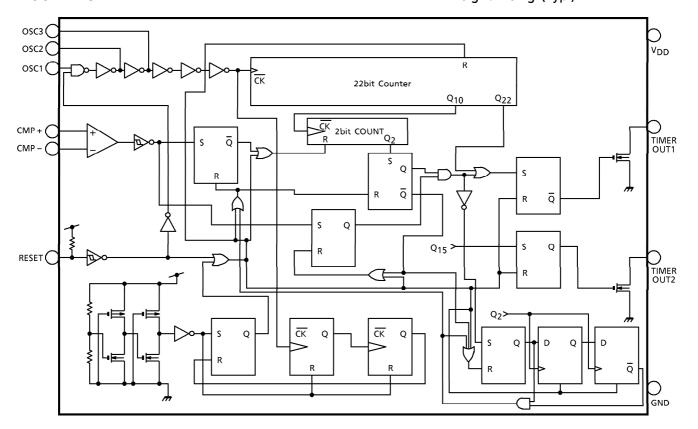
### **FEATURES**

- MOS IC with 22-stage binary counter.
- Built-in initialize circuit.
- Built-in voltage detection comparator.
- Wide range timer setting.
- Low power dissipation current.
- Suitable for Ni-cd battery charger.



# Weight: 0.1g (Typ.)

### **BLOCK DIAGRAM**

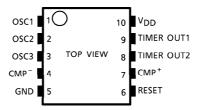


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### **FUNCTION DESCRIPTION ON EACH TERMINAL**

PIN No.	SYMBOL	FUNCTION
1	OSC1	Oscillation input terminal
2	OSC2	Oscillation input terminal
3	OSC3	Oscillation input terminal
4	CMP-	Comparator minus ( – ) side input terminal "L" : Timer mode, "H" : Timer stop
5	GND	GND
6	RESET	Reset terminal (H→L : inside reset)
7	CMP+	Comparator plus (+) side input terminal Comparator reference voltage setting terminal
8	TIMER OUT2	Timer output terminal 2 (TIMER OUT1) (N-ch open drain sink max. 5mA)
9	TIMER OUT1	Timer output terminal 1 (N-ch open drain, sink max. 5mA)
10	V <sub>DD</sub>	Power supply voltage

### **PIN CONNECTION**



### TRUTH TABLE

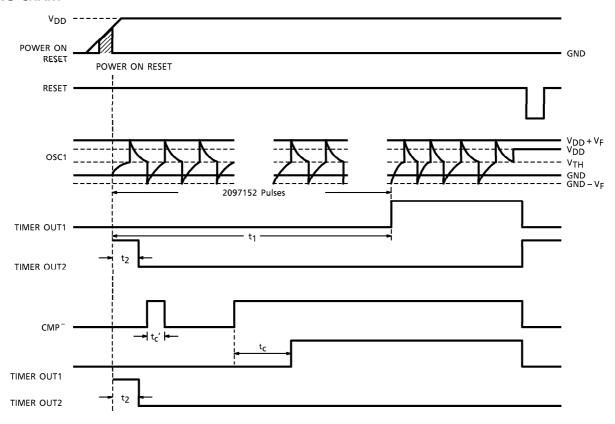
MODE		INPUT		OUTPUT		
IVIODE	RESET	CMP+	CMP-			
1	L	(*)	(*)	L		
2	Н	Н	L	Timer mode		
3	Н	L	Н	Timer over-voltage detecting mode		

(\*) : H or L

Turning the power supply on, "Power on Reset" is operated and output level is "L".

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# **TIMING CHART**



(\*) :  $t_{\text{C}}^{\,\prime} \! < \! t_{\text{C}}$  at CMP  $^{\text{-}}$  input "H" Level cancelled

# **MAXIMUM RATINGS** (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Power Supply Voltage	$V_{DD}$	-0.3~7.0	V
Power Dissipation	PD	250~300	mW
Operating Temperature	Topr	<b>- 20∼75</b>	°C
Storage Temperature	T <sub>stg</sub>	<b>-</b> 55∼125	°C
Electrostatic Discharge	ESD (*)	± 200	V
Latch Up Current	ΙL	± 10	mA

(\*) : C = 200pF,  $R = 0\Omega$ , one time discharge

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# **ELECTRICAL CHARACTERISTICS** (Unless otherwise specified, $Ta = 25 \pm 1.5^{\circ}C$ , $V_{DD} = 5.0V$ )

CHARACTERISTIC		SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Operating Voltage		V <sub>opr</sub>	_	_	4.0	5.0	6.0	V
Oscillation Frequency Characteristic		∆fosc1	_	1H C = 4700pF, R = 254.9k $\Omega$ , V <sub>DD</sub> = 5V (f = 582.5Hz)	_	_	10	
		∆fosc2 —		60s C = 1000pF, R = 17.2k $\Omega$ , V <sub>DD</sub> = 5V (f = 34.9kHz)		_	15	%
			_	8H C = $0.01\mu$ F, R = 996.7k $\Omega$ , V <sub>DD</sub> = 5V (f = 72.8Hz)		_	15	
Power Dissipation Current	1	I <sub>QD</sub>		CR OSC. stopping (at reset) V <sub>DD</sub> = 6V	_		130	^
	2	I <sub>DD</sub>		CR OSC. operating (at 60s setting)	_	_	700	μΑ
Power on Reset		$V_{thH}$		V <sub>DD</sub> rise time	1.4	2.5	3.5	V
Release Voltage		$V_{thL}$	_	<b>40</b> μs / V	1.4	2.5	3.5	<b>'</b>

# DC CHARACTERISTICS

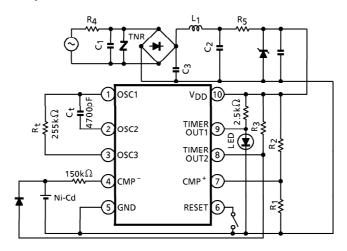
1. Oscillation Input	1. Oscillation Input							
OSC1 Leak Current	lih osc	_	V <sub>IN</sub> = 5.0V	- 1.0	_	1.0	μΑ	
OSC1 Leak Current	IL OSC		V <sub>IN</sub> = 0V	- 1.0	_	1.0	μΑ	
2.CMP+, CMP- Terminal								
CMP Offset Voltage	V <sub>off</sub>	_	V <sub>DD</sub> = 5V	- 30	_	30	mV	
Offset Supply Voltage Change	$_{\Delta}V_{off}$		V <sub>DD</sub> = 4∼6V	- 10		10	mV	
CMP+, CMP- Leak	IH CMP+, -		V <sub>IN</sub> = 5.0V	- 1.0	_	1.0	^	
Current	IIL CMP+, -	_	V <sub>IN</sub> = 0V	- 1.0	_	1.0	$\mu$ <b>A</b>	
Input Dynamic Range	_		_	0	_	V <sub>DD</sub> - 2.5	٧	
3. Reset Terminal								
Leak Current	IHR	_	V <sub>IN</sub> = 5.0V	- 1.0	_	1.0	$\mu$ A	
Input Pull Up Resistance	R <sub>3</sub>		_	490	700	910	kΩ	
4. Timer Out Terminal								
Timer Out1, 2 Sink Current	lTS	_	V <sub>OL</sub> = 0.3V	_	_	5	mA	
Timer Out Offleak Current	I <sub>TLH1, 2</sub>	_	V <sub>IN</sub> = 0~5.0V	- 1.0		1.0	μΑ	

### **FUNCTION CHARACTERISTICS**

CHARACTERISTICS	SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
	∆T <sub>1</sub>	_	C = 4700pF, R = 254.9k $\Omega$ , V <sub>DD</sub> = 5V (1H setting)	_	_	10	
Timer Precision (TIMER OUT1)	∆T <sub>2</sub>	_	C = 1000pF, R = 17.2k $\Omega$ , VDD = 5V (60s setting)	_	_	15	%
			C = 0.01 $\mu$ F, R = 966.7k $\Omega$ , V <sub>DD</sub> = 5V (8H setting)		_		
CMP Detecting Timer Precision	t <sub>C</sub>	_	C = 4700pF, R = 254.9k $\Omega$ , V <sub>DD</sub> = 5V (1H)	- 50	3.5s	50	%
Timer2 Precision (TIMER OUT2)	∆T3	_	C = 4700pF, R = 254.9k $\Omega$ , V <sub>DD</sub> = 5V (1H setting)	- 10	28.12	10	%

### **APPLICATION CIRCUIT (Example)**

1 hour setting



### Timer setting time

$$T = 2^{21} \cdot C_{t} \cdot R_{t} \cdot \ell n \ \left\{ \frac{V_{DD}^{2} - V_{f}^{2}}{V_{TH} \ (V_{DD} - V_{TH})} \right\}$$

T: Timer setting time (s) C<sub>t</sub> (F) : Capacitor

 $R_t$  ( $\Omega$ ) : Resistance  $V_{TH} = 1.95$  (V) : Voltage of OSC. first stage circuit  $V_f = 0.7$  (V) : Voltage of input protection diode (1Pin)

### (\*) Recommendation of timer setting

TIMER SET UP	R <sub>t</sub>	Ct
About 60s	17.2k $\Omega$	1000pF
About 1Hour	254.9k $\Omega$	4700pF
About 8Hour	966.7k $\Omega$	0.01μF

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# PACKAGE DIMENSIONS SSOP10-P-225-1.00 Unit : mm 0.6TYP 1.0 5.7MAX 5.2±0.2 7.70 7.

Weight: 0.1g (Typ.)

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000707EBA

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